Vishay General Semiconductor

Surface Mount Glass Passivated Rectifier





T_{.1} max.

DO-214BA (GF1)

175 °C

technique is covered by patent No. 3,996,602, brazed-lead assembly by Patent No. 3,930,306 and lead forming by Patent No. 5,151,846

PRIMARY CHARACTERISTICS									
I _{F(AV)}	1.0 A								
V _{RRM}	50 V to 1000 V								
I _{FSM}	30 A								
V _F	1.1 V, 1.2 V								
I _R	5.0 μΑ								

FEATURES

 Superectifier structure for high reliability condition



ROHS COMPLIANT

- Patented glass-plastic encapsulation technique
- · Ideal for automated placement
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214BA, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	GF1A	GF1B	GF1D	GF1G	GF1J	GF1K	GF1M	UNIT
Device marking code		GA	GB	GD	GG	GJ	GK	GM	
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at T_L = 125 °C	I _{F(AV)}	1.0					А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30					А		
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175					°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)													
PARAMETER	TEST CONDITIONS		SYMBOL	GF1A	GF1B	GF1D	GF1G	GF1J	GF1K	GF1M	UNIT		
Maximum instantaneous forward voltage	1.0 A		V _F	1.1 1.2				1.1 1.2		1.1 1.2		.2	v
Maximum DC reverse current at rated DC blocking voltage		T _A = 25 °C T _A = 125 °C	I _R	5.0 50						μΑ			
Typical reverse recovery time	l _F = 0.5 I _{rr} = 0.2	A, I _R = 1.0 A, 5 A	t _{rr}	3.0					μs				
Typical junction capacitance	4.0 V, 1	MHz	CJ	15					pF				

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)									
PARAMETER	SYMBOL	GF1A GF1B GF1D GF1G GF1J GF1K GF1						GF1M	UNIT
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}	80 26					°C/W		

Note:

(1) Thermal resistance from junction to ambient and from junction to lead, P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)										
PREFERRED P/N	UNIT WEIGHT (g)	REFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE						
GF1J-E3/67A	0.104	67A	1500	7" diameter plastic tape and reel						
GF1J-E3/5CA	0.104	5CA	6500	13" diameter plastic tape and reel						
GF1JHE3/67A ⁽¹⁾	0.104	67A	1500	7" diameter plastic tape and reel						
GF1JHE3/5CA ⁽¹⁾	0.104	5CA	6500	13" diameter plastic tape and reel						

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \ ^{\circ}C \text{ unless otherwise noted})$

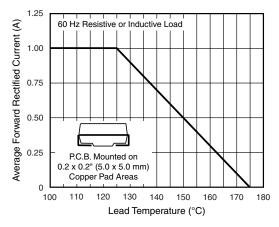


Figure 1. Forward Current Derating Curve

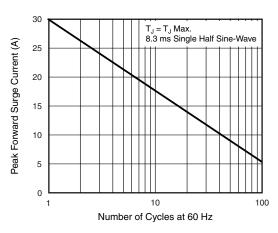


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



GF1A thru GF1M

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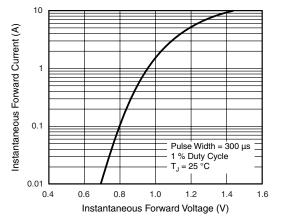


Figure 3. Typical Instantaneous Forward Characteristics

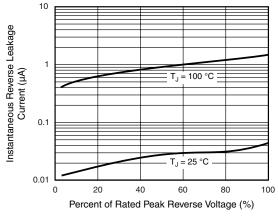


Figure 4. Typical Reverse Characteristics

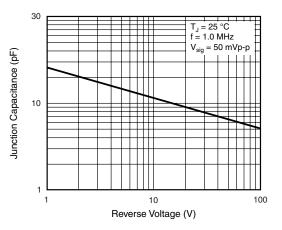


Figure 5. Typical Junction Capacitance

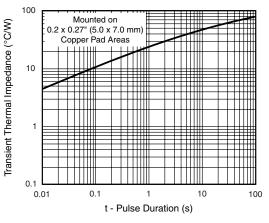
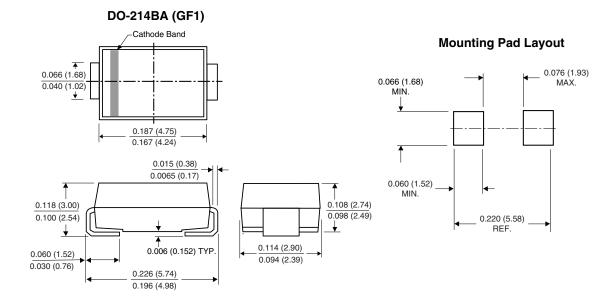


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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